

Features

- Complete 1.3GHz single chip system for Digital Terrestrial Television applications
- Selectable reference division ratio, compatible with (DTT) requirements
- Optimised for low phase noise, with comparison frequencies up to 4MHz
- No RF prescaler
- Selectable reference/comparison frequency output
- Four selectable I²C bus address
- I²C fast mode compliant and compatible with 3.3 and 5V logic levels
- Four switching ports
- ESD protection, (Normal ESD Handling procedures should be observed)

Applications

- Digital Satellite ,Cable and Terrestrial tuning systems
- Communications systems

Ordering Information

SP5730A/KG/MP1S Sticks
SP5730A/KG/MP1T Tape and Reel
SP5730A/KG/QP1S Sticks
SP5730A/KG/QP1T Tape and Reel

Description

The SP5730 is a single chip frequency synthesiser designed for tuning systems up to 1.3GHz and is optimised for digital terrestrial applications.

The RF preamplifier interfaces direct with the RF programmable divider, which is of MN+A construction so giving a step size equal to the loop comparison frequency and no prescaler phase noise degradation over the RF operating range.

The comparison frequency is obtained either from an on-chip crystal controlled oscillator, or from an external source. The oscillator frequency, F_{ref}, or phase comparator frequency, F_{comp}, can be switched to the REF/COMP output providing a reference frequency for a second frequency synthesiser.

The synthesiser is controlled via an I²C bus and is fast mode compliant. It can be hard wired to respond to one of four addresses to enable two or more synthesisers to be used on a common bus.

The device contains four switching ports P0-P3.

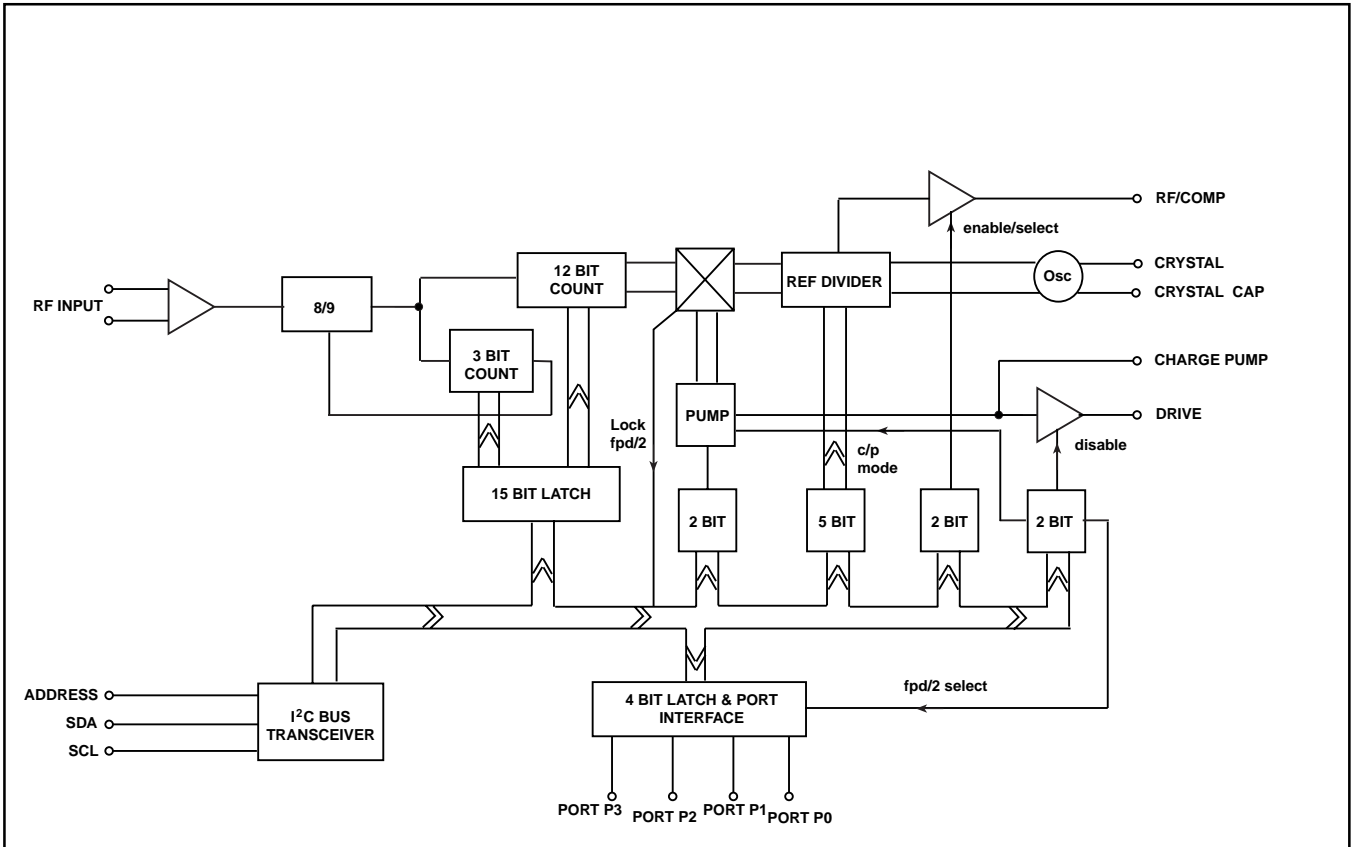
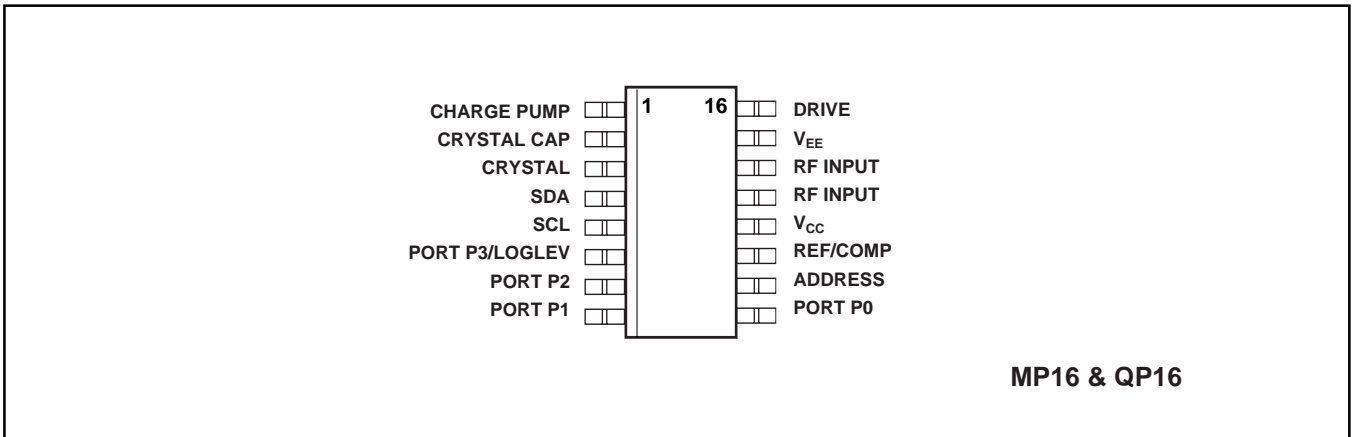


Figure 1 Block diagram



MP16 & QP16

Figure 2 Pin connections top view

Electrical Characteristics

Tamb= -40°C to 85°C, V_{CC}= 4.5 to 5.5V

These characteristics are guaranteed by either production test or design. They apply within the specified ambient temperature and supply voltage unless otherwise stated.

| Characteristic | Pin | Value | | | Units | Conditions |
|---------------------------------------|-------|-------|-----|-----|-------|---|
| | | Min | Typ | Max | | |
| Supply current | | | | 20 | mA | |
| RF input voltage | 13,14 | 12.5 | | 300 | mVrms | 100 MHz – 1.3GHz, see Figure. 4 |
| RF input voltage | 13,14 | 40 | | 300 | mVrms | 50MHz - 100MHz, see Figure 4 |
| RF input impedance | 13,14 | | | | | See Figure. 5 |
| SDA, SCL | 4, 5 | | | | | |
| Input high voltage | | 3 | | 5.5 | V | 5V I ² C logic selected |
| Input low voltage | | 0 | | 1.5 | V | 5V I ² C logic selected |
| Input high voltage | | 2.3 | | 3.5 | V | 3V3 I ² C logic selected |
| Input low voltage | | 0 | | 1 | V | 3V3 I ² C logic selected |
| Input high current | | | | 10 | μA | Input voltage =Vcc |
| Input low current | | | | 10 | μA | Input voltage = Vee |
| Leakage current | | | | 10 | μA | Vee = Vcc |
| Hysteresis | | | 0.4 | | V | |
| SDA output voltage | 4 | | | 0.4 | V | Isink = 3mA |
| | | | | 0.6 | V | Isink = 6mA |
| SCL clock rate | 5 | | | 400 | kH | |
| Charge pump output current | 1 | | | | | See Table 6 Vpin1 = 2V |
| Charge pump output leakage | 1 | | 3 | 10 | nA | Vpin1 = 2V, Vcc = 5V, +25°C |
| Charge pump drive output current | 16 | 0.5 | | | mA | Vpin16 = 0.7V |
| Crystal frequency | 2,3 | 2 | | 20 | MHz | See Figure 3 for application |
| Recommended crystal series resistance | | 10 | | 200 | Ω | 4 MHz “parallel resonant” crystal. |
| External reference input Frequency | 3 | 2 | | 20 | MHz | Sinewave coupled through 10 nF blocking capacitor |
| External reference drive level | 3 | 0.2 | | 0.5 | Vpp | Sinewave coupled through 10 nF blocking capacitor |

Electrical Characteristics (continued)T_{amb}= -40^oC to 85^oC, V_{cc}= 4.5 to 5.5V

These characteristics are guaranteed by either production test or design. They apply within the specified ambient temperature and supply voltage unless otherwise stated.

| Characteristic | Pin | Value | | | Units | Conditions |
|--|-----|---------------|-------------|------------------------------|----------------------|---|
| | | Min | Typ | Max | | |
| Buffered REF/COMP output output amplitude output impedance | 11 | | 0.35 250 | | V _{pp} Ω | AC coupled 0.5-20MHz Enabled by bit RE= 1 See note 2 |
| Phase detector Comparison frequency | | | | 4 | MHz | |
| Equivalent phase noise at phase detector | | -152 -158 | | | dBc/Hz | SSB, within loop bandwidth F _{comp} = 2MHz F _{comp} = 125kHz |
| RF division ratio | | 56 | | 32767 | | |
| Reference division ratio | | | | | | See Table 1 |
| Output ports P0 - P3 sink current Leakage current | 6-9 | 2 | | 10 | mA μA | See Note 1 V _{port} = 0.7 V _{port} = V _{cc} |
| Address Select Input high current Input low current | 10 | | | 1 -0.5 | mA mA | See Figure 4 Table 3 V _{in} = V _{cc} V _{in} = V _{ee} |
| Logic level select Input high level Input low level Input current | 6 | 3 0 -10 | | V _{cc} 1.5 10 | V V μA | See note 3 5V I ² C logic selected, or open circuit 3V3 I ² C logic selected V _{in} = V _{ee} to V _{cc} |

Notes:

1. Output ports high impedance on power up, with data, clock, and enable at logic '0'
2. If the REF/COMP output is not used, the output should be left open circuit or connected to V_{cc}, and disabled by setting RE = 0
3. Bi-directional port. When used as an output, the input logic state is ignored. When used as an input the port should be switched in to high impedance (off) state.

Absolute Maximum Ratings

All voltages are referred to Vee at 0V

| Characteristic | Min | Max | Units | Conditions |
|---|------|---------|-------------------|---|
| Supply voltage, Vcc | -0.3 | 7 | V | Transient |
| RF input voltage | | 2.5 | Vpp | Differential |
| All I/O port DC offsets | -0.3 | Vcc+0.3 | V | |
| SDA and SCL DC offset | -0.3 | 6V | $\frac{V}{\circ}$ | |
| Storage temperature | -55 | +150 | \circ C | |
| Junction temperature | | 150 | C | |
| QP16 thermal resistance, chip to ambient | | 80 | \circ C/W | |
| chip to case | | 20 | \circ C/W | |
| Power consumption at Vcc = 5.5V | | 83 | mW | All ports off |
| ESD protection | 2 | | kV | mil std 883 latest revision method 3015 class 1 |

Functional Description

The SP5730 contains all the elements necessary, with the exception of a frequency reference, loop filter and external high voltage transistor, to control a varicap tuned local oscillator, so forming a complete PLL frequency synthesised source. The device allows for operation with a high comparison frequency and is fabricated in high speed logic, which enables the generation of a loop with good phase noise performance. It can also be operated with comparison frequencies appropriate for frequency offsets as required in digital terrestrial (DTT) receivers. The block diagram is shown in Figure 2.

The RF input signal is fed to an internal preamplifier, which provides gain and reverse isolation from the divider signals. The output of the preamplifier interfaces direct with the 15-bit fully programmable divider, which is of MN+A architecture, where the dual modulus prescaler is 8/9, the A counter is 3-bits, and the M counter is 12 bits.

The output of the programmable divider is fed to the phase comparator where it is compared in both phase and frequency domain with the comparison frequency. This frequency is derived either from the on-board crystal controlled oscillator or from an external reference source. In both cases the reference frequency is divided down to the comparison frequency by the reference divider which is programmable into 1 of 29 ratios as detailed in Table 1.

The output of the phase detector feeds a charge pump and loop amplifier section, which when used with an external high voltage transistor and loop filter, integrates the current pulses into the varactor line voltage.

The programmable divider output Fpd divided by two can be switched to port P0 by programming the device into test mode. The test modes are described in Table 4.

Programming

The SP5730 is controlled by an I²C data bus and is compatible with both standard and fast mode formats and with I²C data generated from nominal 3.3V and 5V sources. The I²C logic level is selected by the bi-directional port P3/LOGLEV. 5V logic levels are selected by connecting P3/LOGLEV to Vcc or leaving open circuit and 3.3V by connecting to ground. If this port is used as an input the P3 data should be programmed to high impedance. If used as an output 5V logic only levels can be used and in this case the logic state imposed by the port on the input is ignored.

Data and Clock are fed in on the SDA and SCL lines respectively as defined by I²C bus format. The synthesiser can either accept data (write mode), or send data (read mode). The LSB of the address byte (R/W) sets the device into write mode if it is low, and read mode if it is high. Table 2 illustrates the format of the data. The device can be programmed to respond to several addresses, which enables the use of more than one synthesiser in an I²C bus system. Table 3 shows how the address is selected by applying a voltage to the 'address' input.

When the device receives a valid address byte, it pulls the SDA line low during the acknowledge period, and during following acknowledge periods after further data bytes are received. When the device is programmed into read mode, the controller accepting the data must pull the SDA line low during all status byte acknowledge periods to read another status byte. If the controller fails to pull the SDA line low during this period, the device generates an internal STOP condition, which inhibits further reading.

Write mode

With reference to Table 2, bytes 2 and 3 contain frequency information bits 2^{14} - 2^0 inclusive. Byte 4 and byte 5 control the reference divider ratio, see Table 1, charge pump setting, see Table 6, REF/COMP output, see Table 7, output ports and test modes, see Table 4.

After reception and acknowledgement of a correct address (byte 1), the first bit of the following byte determines whether the byte is interpreted as a byte 2 or 4, a logic '0' indicating byte 2, and a logic '1' indicating byte 4. Having interpreted this byte as either byte 2 or 4 the following data byte will be interpreted as byte 3 or 5 respectively. Having received two complete data bytes, additional data bytes can be entered, where byte interpretation follows the same procedure, without readdressing the device. This procedure continues until a STOP condition is received. The STOP condition can be generated after any data byte, if however it occurs during a byte transmission, the previous byte data is retained. To facilitate smooth fine tuning, the frequency data bytes are only accepted by the device after all 15 bits of frequency data have been received, or after the generation of a STOP condition.

Read mode

When the device is in read mode, the status byte read from the device takes the form shown in Table 2.

Bit 1 (POR) is the power-on reset indicator, and this is set to a logic '1' if the Vcc supply to the device has dropped below 3V (at 25°C), e.g. when the device is initially turned ON. The POR is reset to '0' when the read sequence is terminated by a STOP command. When POR is set high this indicates that the programmed information may have been corrupted and the device reset to power up condition.

Bit 2 (FL) indicates whether the device is phase locked, a logic '1' is present if the device is locked, and a logic '0' if the device is unlocked.

Programmable features

RF programmable divider

Function as described above

Reference programmable divider

Function as described above.

Charge pump current

The charge pump current can be programmed by bits C1-C0 within data byte 5, as defined in Table 6.

Test mode

The test modes are invoked by bits REB, RS, T1 and T0 as described in Table 4.

Reference/Comparison frequency output

The reference frequency F_{ref} or comparison frequency F_{comp} can be switched to the REF/COMP output, function as defined in Table 7. RE and RS default to logic '1' during device power up, thus enabling the comparison frequency F_{comp} at the REF/COMP output.

| R4 | R3 | R2 | R1 | R0 | Ratio |
|----|----|----|----|----|---------------|
| 0 | 0 | 0 | 0 | 0 | 2 |
| 0 | 0 | 0 | 0 | 1 | 4 |
| 0 | 0 | 0 | 1 | 0 | 8 |
| 0 | 0 | 0 | 1 | 1 | 16 |
| 0 | 0 | 1 | 0 | 0 | 32 |
| 0 | 0 | 1 | 0 | 1 | 64 |
| 0 | 0 | 1 | 1 | 0 | 128 |
| 0 | 0 | 1 | 1 | 1 | 256 |
| 0 | 1 | 0 | 0 | 0 | Illegal state |
| 0 | 1 | 0 | 0 | 1 | 5 |
| 0 | 1 | 0 | 1 | 0 | 10 |
| 0 | 1 | 0 | 1 | 1 | 20 |
| 0 | 1 | 1 | 0 | 0 | 40 |
| 0 | 1 | 1 | 0 | 1 | 80 |
| 0 | 1 | 1 | 1 | 0 | 160 |
| 0 | 1 | 1 | 1 | 1 | 320 |
| 1 | 0 | 0 | 0 | 0 | Illegal state |
| 1 | 0 | 0 | 0 | 1 | 6 |
| 1 | 0 | 0 | 1 | 0 | 12 |
| 1 | 0 | 0 | 1 | 1 | 24 |
| 1 | 0 | 1 | 0 | 0 | 48 |
| 1 | 0 | 1 | 0 | 1 | 96 |
| 1 | 0 | 1 | 1 | 0 | 192 |
| 1 | 0 | 1 | 1 | 1 | 384 |
| 1 | 1 | 0 | 0 | 0 | Illegal State |
| 1 | 1 | 0 | 0 | 1 | 7 |
| 1 | 1 | 0 | 1 | 0 | 14 |
| 1 | 1 | 0 | 1 | 1 | 28 |
| 1 | 1 | 1 | 0 | 0 | 56 |
| 1 | 1 | 1 | 0 | 1 | 112 |
| 1 | 1 | 1 | 1 | 0 | 224 |
| 1 | 1 | 1 | 1 | 1 | 448 |

X = don't care

Table 1 Reference division ratio

| | MSB | | | | | LSB | | | | |
|----------------------|----------------|-----------------|-----------------|-----------------|-----------------|-----------------|----------------|----------------|---|--------|
| Address | 1 | 1 | 0 | 0 | 0 | MA1 | MA0 | 0 | A | Byte 1 |
| Programmable divider | 0 | 2 ¹⁴ | 2 ¹³ | 2 ¹² | 2 ¹¹ | 2 ¹⁰ | 2 ⁹ | 2 ⁸ | A | Byte 2 |
| Programmable divider | 2 ⁷ | 2 ⁶ | 2 ⁵ | 2 ⁴ | 2 ³ | 2 ² | 2 ¹ | 2 ⁰ | A | Byte 3 |
| Control Data | 1 | T1 | T0 | R4 | R3 | R2 | R1 | R0 | A | Byte 4 |
| Control Data | C1 | C0 | RE | RS | P3 | P2 | P1 | P0 | A | Byte 5 |

Table 2 Write data format (MSB is transmitted first)

| | MSB | | | | | LSB | | | | |
|-------------|-----|----|---|---|---|-----|-----|---|---|--------|
| Address | 1 | 1 | 0 | 0 | 0 | MA1 | MA0 | 1 | A | Byte 1 |
| Status byte | POR | FL | 0 | 0 | 0 | 0 | 0 | 0 | A | Byte 2 |

Table 2 Read data format (MSB is transmitted first)

- A : Acknowledge bit
- MA1,MA0 : Variable address bits (see Table 3)
- $2^{14} - 2^0$: Programmable division ratio control bits
- R4-R0 : Reference division ratio select (see Figure 3)
- C1, C0 : Charge pump current select (see Figure 6)
- RE : REF/COMP output enable
- RS : REF/COMP output select when RE=1 (see Figure 2)
- T1-T0 : Test mode control bits
- P3-P0 : P3 - P0 port output states
- POR : Power on reset indicator
- FL : Phase lock flag

| MA1 | MA0 | Address input voltage level |
|-----|-----|-----------------------------|
| 0 | 0 | 0 - 0.1Vcc |
| 0 | 1 | Open circuit |
| 1 | 0 | 0.4Vcc - 0.6Vcc # |
| 1 | 1 | 0.9Vcc - Vcc |

Programmed by connecting a 30kΩ ± 5% resistor between pin 10 and Vcc

Table 3 Address selection

| RE.RS | T1 | T0 | Test mode description |
|-------|----|----|--|
| 0 | 0 | 0 | Normal operation |
| 1 | 0 | 0 | Normal operation Port P0 = Fpd/2 |
| X | 0 | 1 | Charge pump sink.* Status byte FL set to logic '0' |
| X | 1 | 0 | Charge pump source * Status byte FL set to logic '0' |
| X | 1 | 1 | Charge pump disabled * Status byte FL set to logic '1' |

*clocks need to be present on crystal and RF inputs to enable charge pump test modes and to toggle Status byte bit FL

X = Dont Care

Table 4 Test modes

| C1 byte 5, bit 1 | C0 byte 5, bit 2 | Current in μA | | |
|---------------------|---------------------|--------------------------|----------|----------|
| | | Min | Typ | Max |
| 0 | 0 | + - 116 | + - 155 | + - 194 |
| 0 | 1 | + - 247 | + - 330 | + - 412 |
| 1 | 0 | + - 517 | + - 690 | + - 862 |
| 1 | 1 | + - 1087 | + - 1450 | + - 1812 |

Table 6 Charge pump current

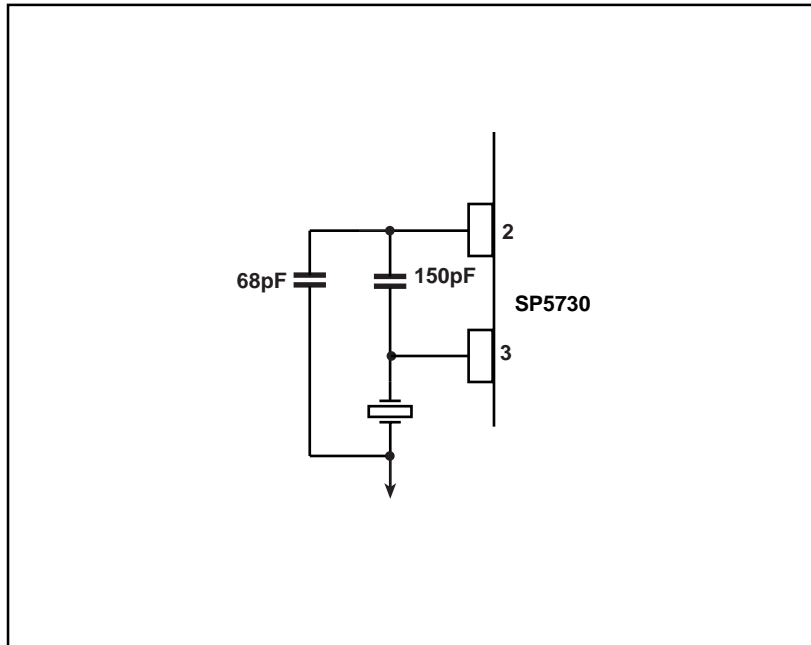


Figure 3 XTAL oscillator application

| RE | RS | REF/COMP OUTPUT |
|----|----|--|
| 0 | 0 | High impedance |
| 0 | 1 | High impedance Test mode enabled, see Figure 5 |
| 1 | 0 | Fref selected |
| 1 | 1 | Fcomp selected |

X = don't care

Table 7; REF/COMP output

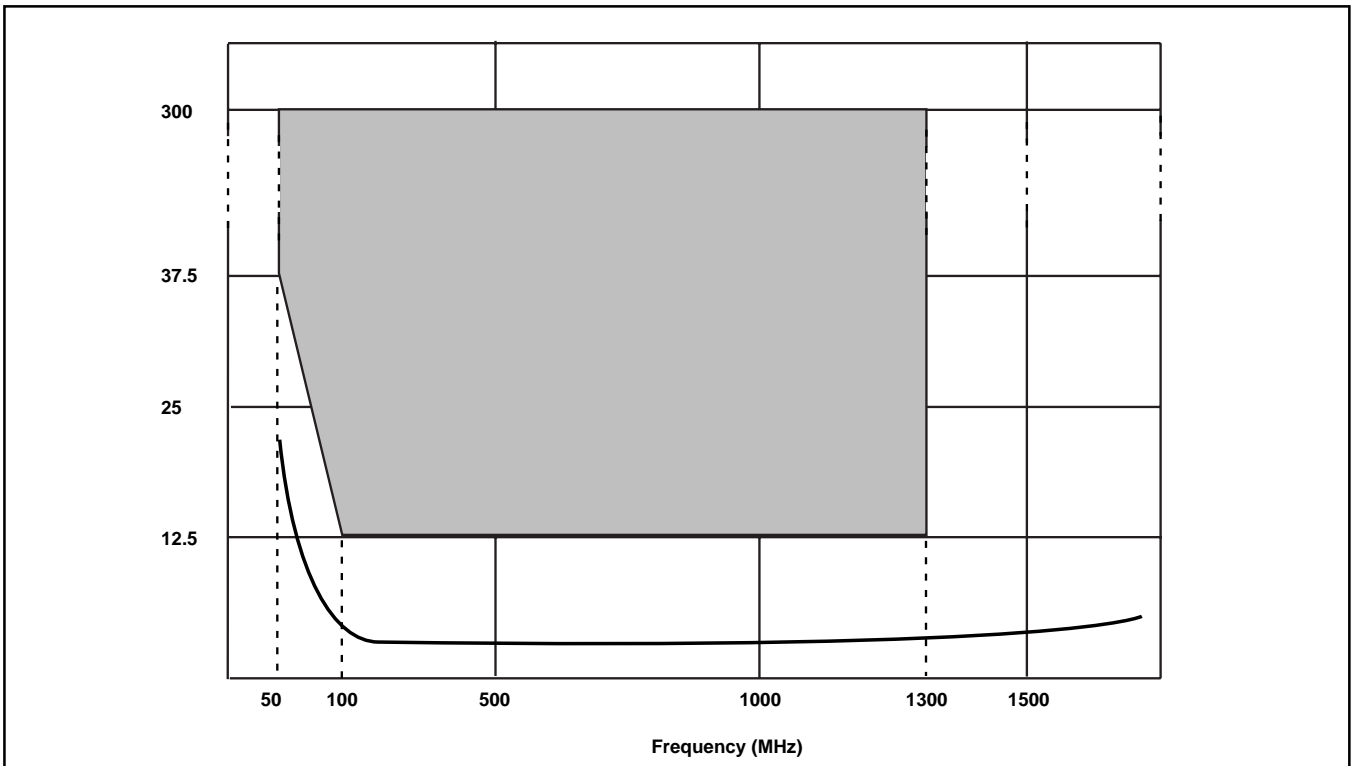


Figure 4 Typical RF input sensitivity

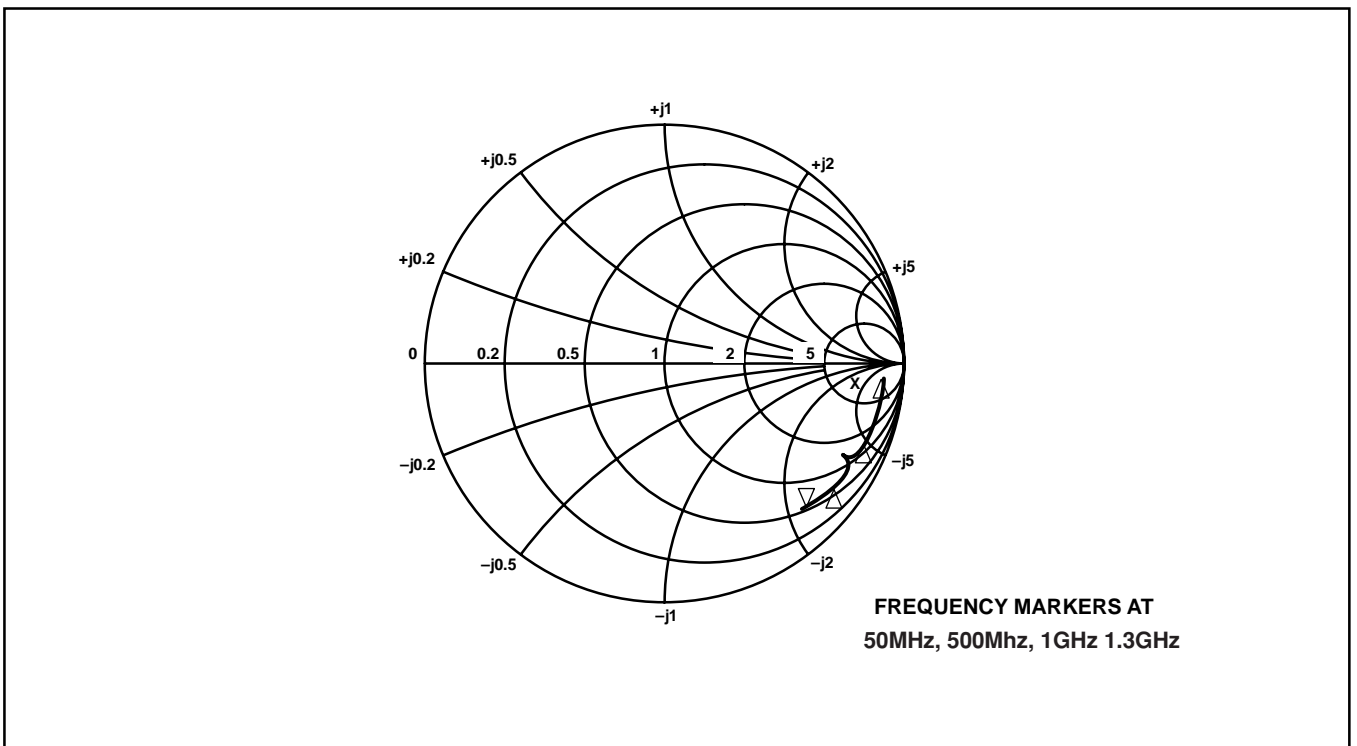


Figure 5 RF input impedance

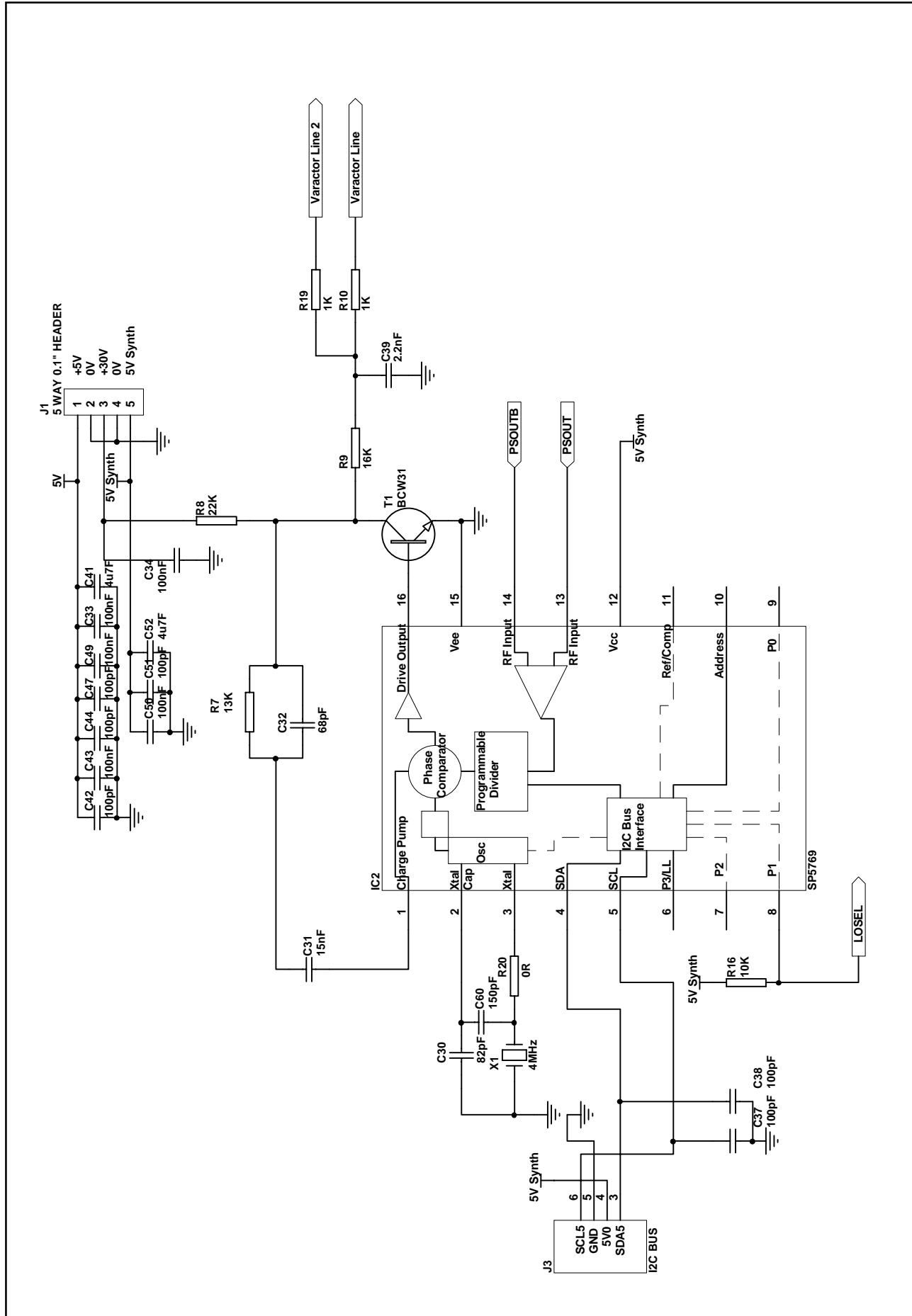


Figure 6 evaluation board schematic

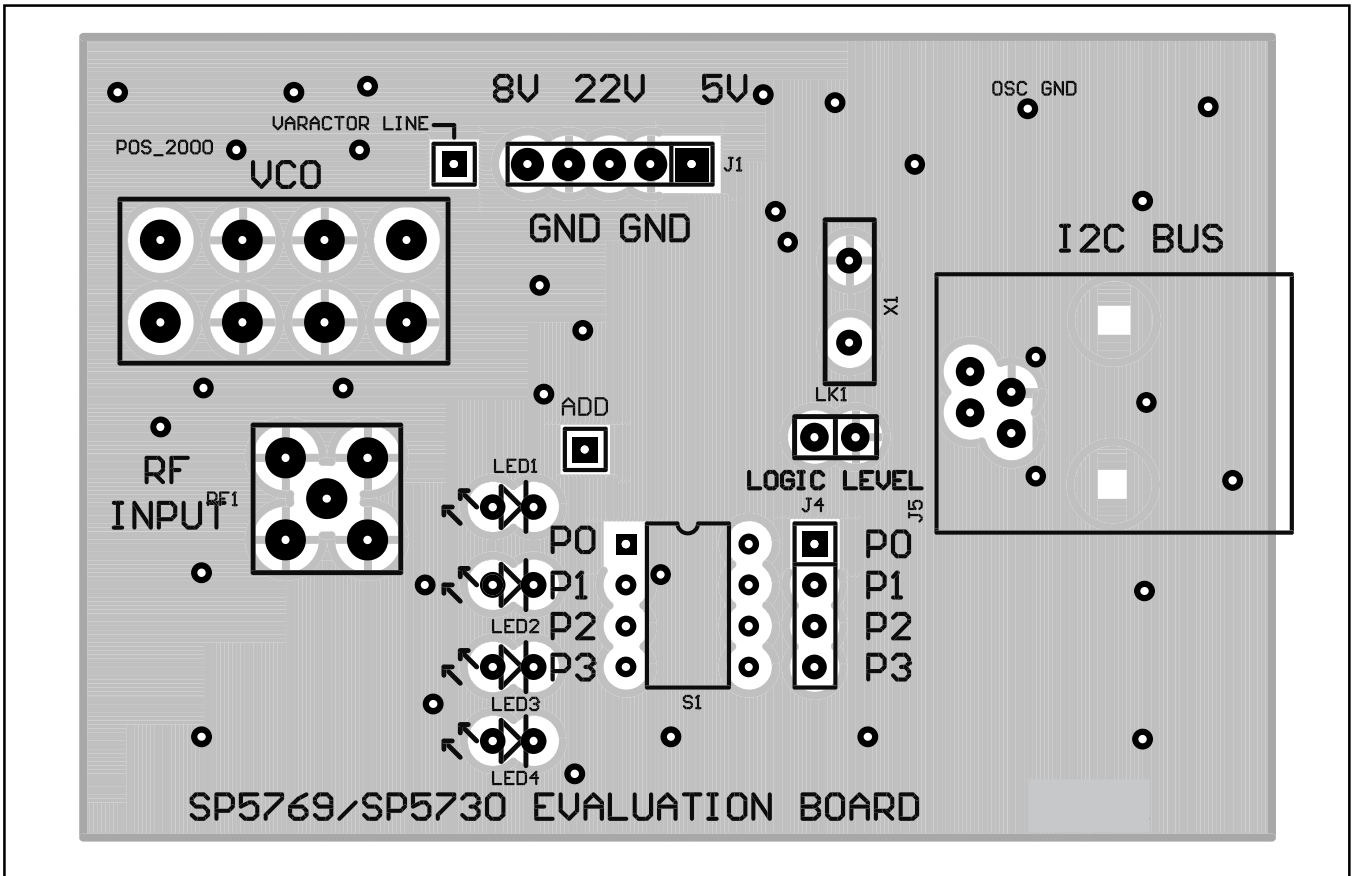


Figure 7 Evaluation board (top view)

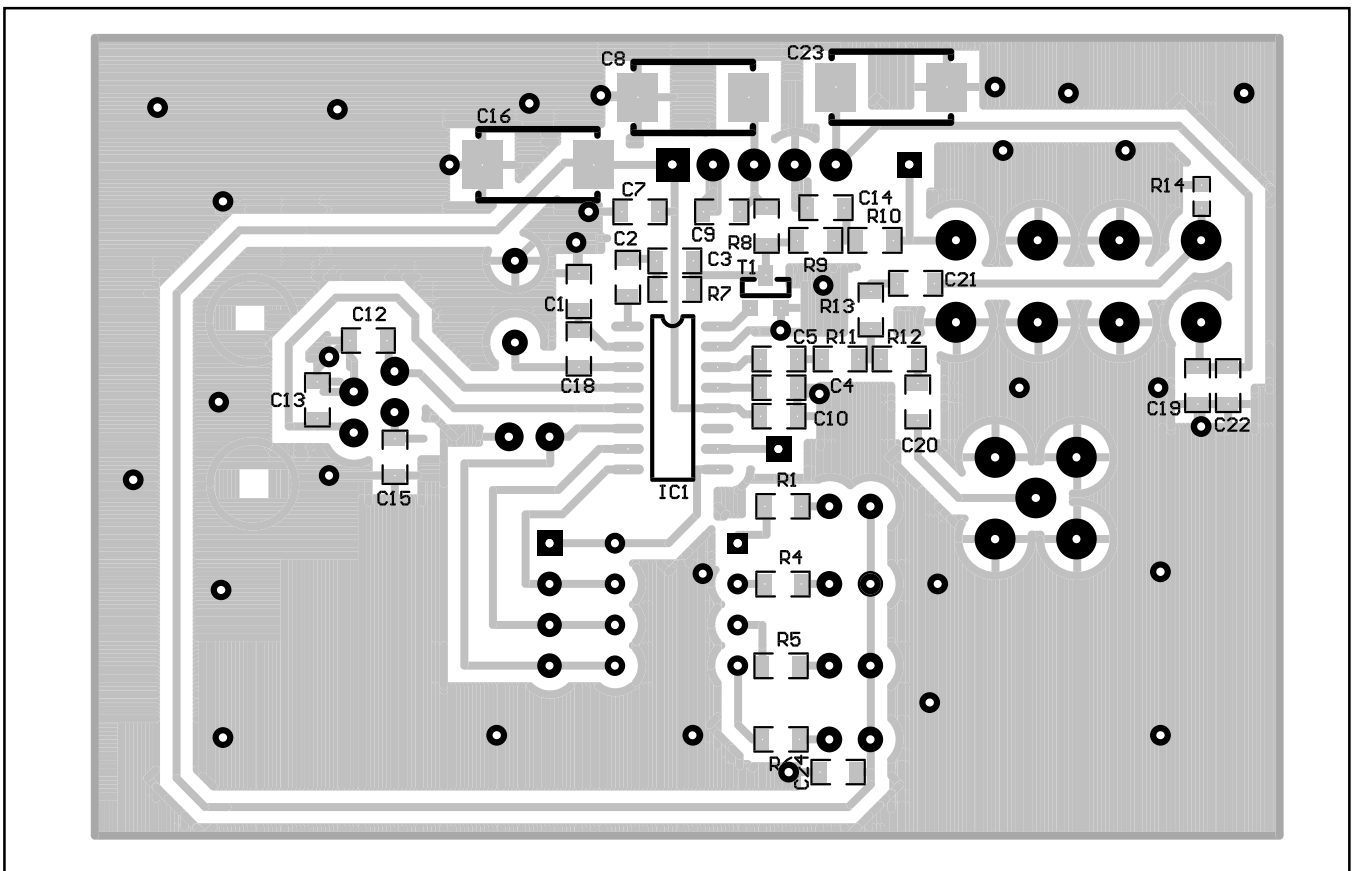
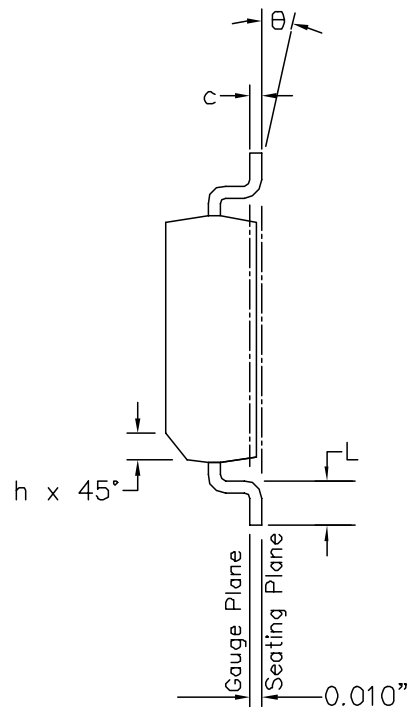
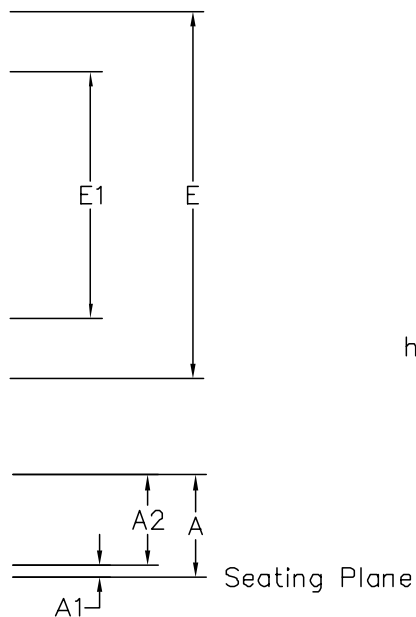
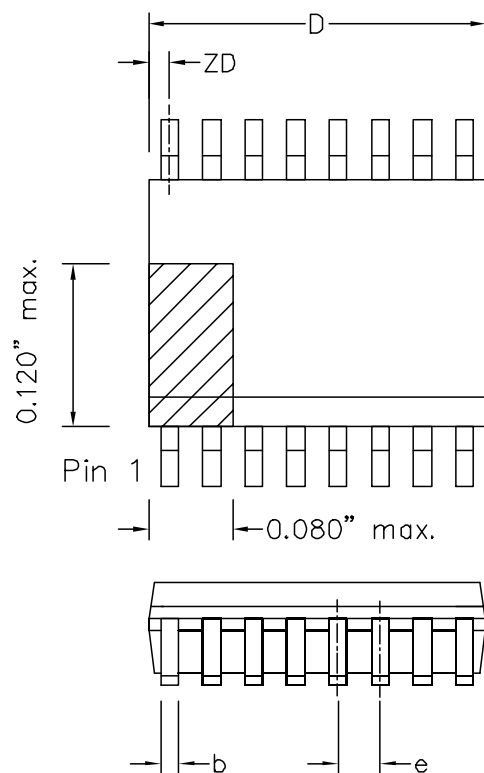


Figure 8 Evaluation board (bottom view)



| Symbol | Control Dimensions in inches | | Altern. Dimensions in millimetres | |
|-----------------------------------|---------------------------------|-------|--------------------------------------|------|
| | MIN | MAX | MIN | MAX |
| A | 0.053 | 0.069 | 1.35 | 1.75 |
| A1 | 0.004 | 0.010 | 0.10 | 0.25 |
| A2 | — | 0.059 | — | 1.50 |
| D | 0.189 | 0.197 | 4.80 | 5.00 |
| ZD | 0.009 | REF. | 0.23 | REF. |
| E | 0.228 | 0.244 | 5.79 | 6.20 |
| E1 | 0.150 | 0.157 | 3.81 | 3.99 |
| L | 0.016 | 0.050 | 0.41 | 1.27 |
| e | 0.025 | BSC. | 0.64 | BSC. |
| b | 0.008 | 0.012 | 0.20 | 0.30 |
| c | 0.007 | 0.010 | 0.18 | 0.25 |
| θ | 0° | 8° | 0° | 8° |
| h | 0.010 | 0.020 | 0.25 | 0.50 |
| Pin features | | | | |
| N | 16 | | | |
| Conforms to JEDEC MO-137AB Iss. A | | | | |

This drawing supersedes
418/ED/51617/001 (Swindon/Roborough)
TD/D 1028 (Oldham)

Notes:

1. The chamfer on the body is optional. If it is not present, a visual index feature, e.g. a dot, must be located within the cross-hatched area.
2. Controlling dimensions are in inches.
3. Dimension D do not include mould flash, protrusion or gate burrs. These shall not exceed $0.006''$ per side.
4. Dimension $E1$ do not include inter-lead flash or protrusion. These shall not exceed $0.010''$ per side.
5. Dimension b does not include dambar protrusion/intrusion. Allowable dambar protrusion shall be $0.004''$ total in excess of b dimension.

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MITEL SEMICONDUCTOR

Title:
Package Outline Drawing for
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Drawing Number
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